

Device Modeling Report

COMPONENTS:

DIODE/ SCHOOTTKY RECTIFIER /STANDARD

PART NUMBER: EP10QY03

MANUFACTURER: NIEC

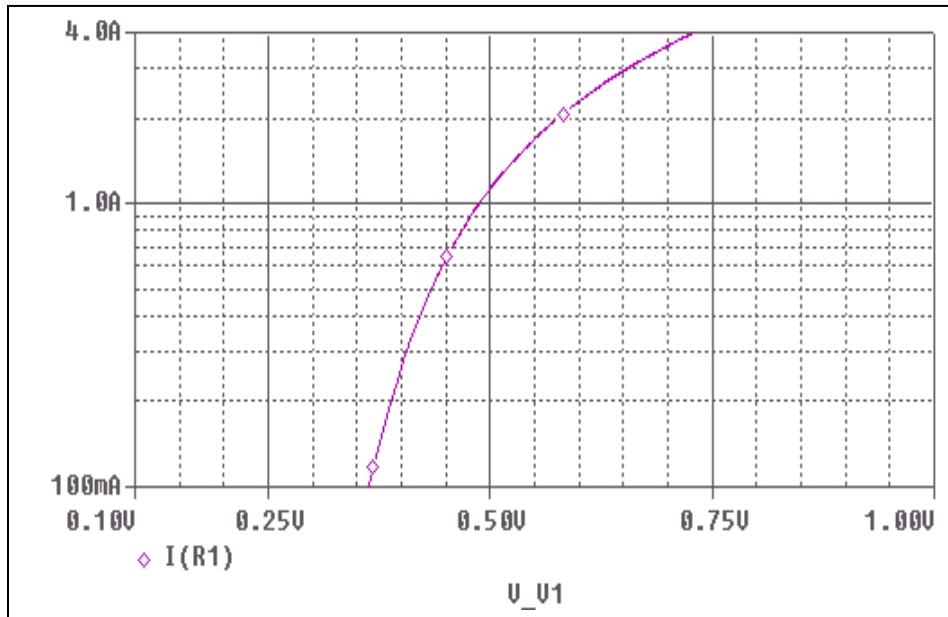


Bee Technologies Inc.

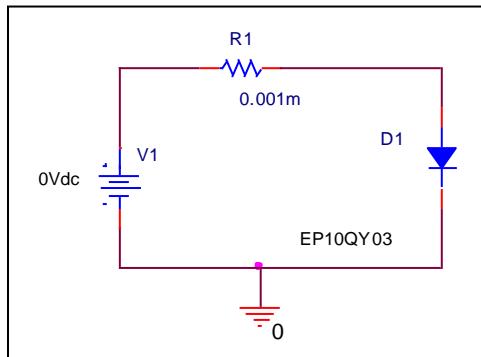
PSpice model parameter	Model description
IS	Saturation Current
N	Emission Coefficient
RS	Series Resistance
IKF	High-injection Knee Current
CJO	Zero-bias Junction Capacitance
M	Junction Grading Coefficient
VJ	Junction Potential
ISR	Recombination Current Saturation Value
BV	Reverse Breakdown Voltage(a positive value)
IBV	Reverse Breakdown Current(a positive value)
TT	Transit Time
EG	Energy-band Gap

Forward Current Characteristic

Circuit Simulation Result

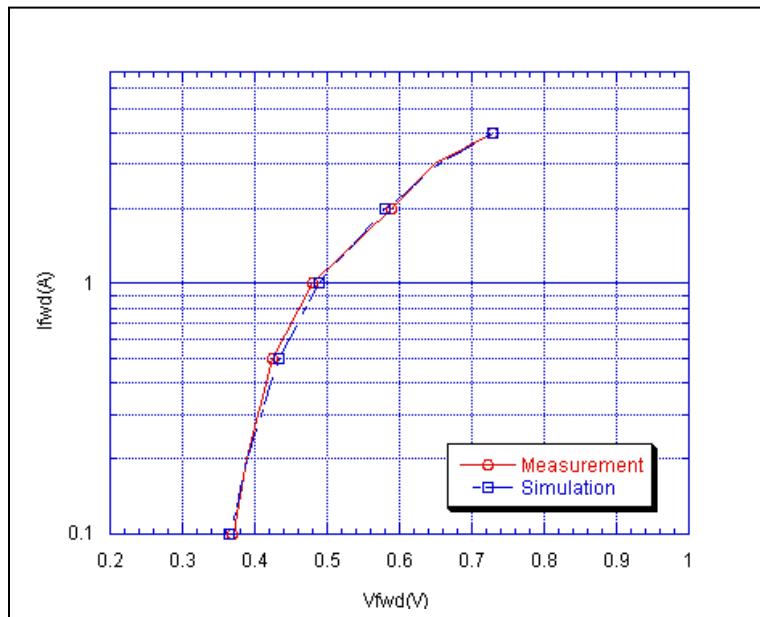


Evaluation Circuit



Comparison Graph

Circuit Simulation Result

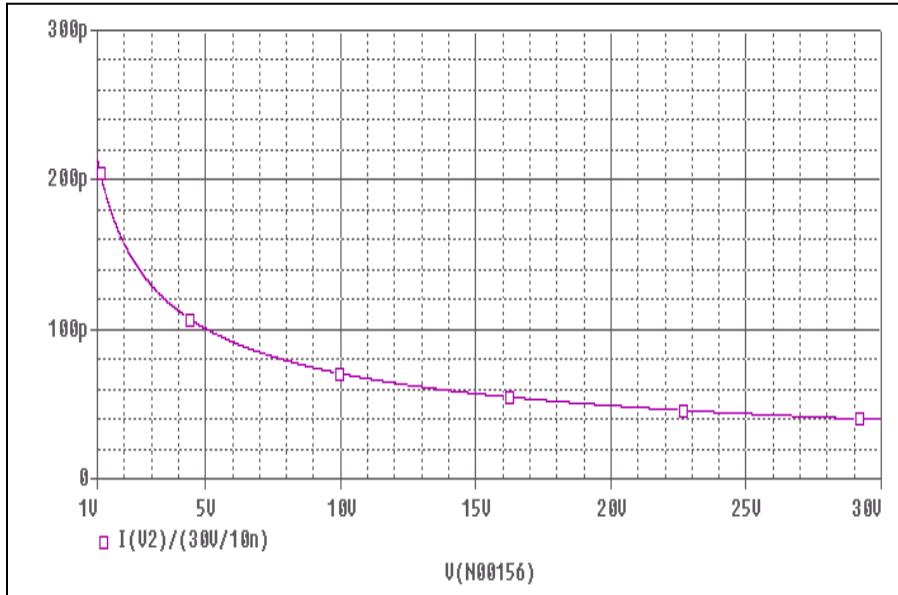


Simulation Result

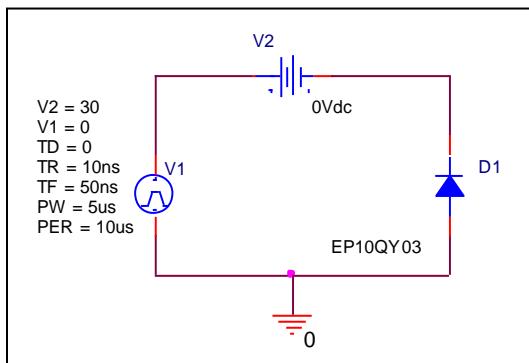
$I_{fwd}(A)$	$V_{fwd}(V)$ Measurement	$V_{fwd}(V)$ Simulation	%Error
0.1	0.370	0.365	-1.35
0.2	0.390	0.388	-0.51
0.5	0.425	0.433	1.88
1	0.480	0.488	1.67
2	0.590	0.579	-1.86
3	0.650	0.655	0.77
4	0.730	0.725	-0.68

Capacitance Characteristic

Circuit Simulation Result

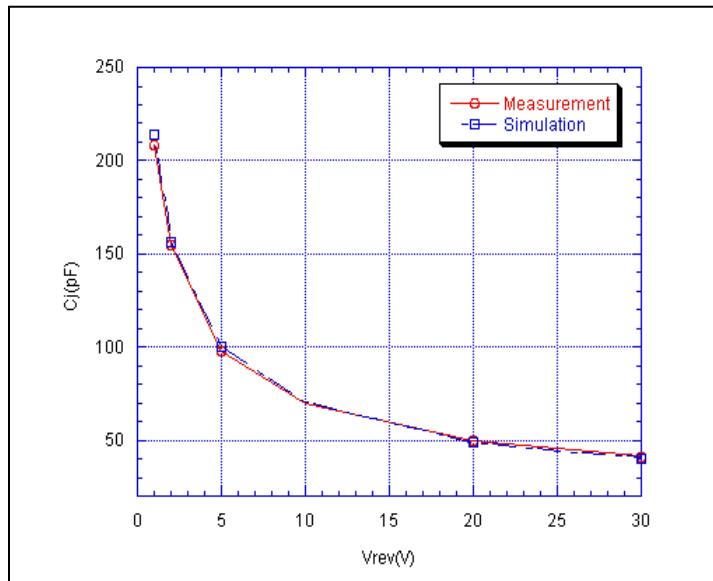


Evaluation Circuit



Comparison Graph

Circuit Simulation Result



Simulation Result

V_{rev} (V)	C_j (pF) Measurement	C_j (pF) Simulation	%Error
1	208.000	213.700	2.74
2	155.000	156.400	0.90
5	98.000	100.500	2.55
10	70.000	70.300	0.43
20	50.000	48.900	-2.20
30	41.000	39.800	-2.93